

SLOVENSKI STANDARD SIST EN 120005:2002

01-september-2002

Blank detail specification: Photodiodes, photodiode arrays (not intended for fibre optic applications)

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VFB: Photodioden, Photodioden-Zeilen (nicht für faseroptische Anwendungen)

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SPC: Photodiodes, réseaux de photodiodes (non destinées aux applications pour les fibres optiques)

SIST EN 120005:2002

Ta slovenski standard je istoveten z: EN 120005;1992

ICS:

31.260 Optoelektronika, laserska

Optoelectronics. Laser

oprema equipment

SIST EN 120005:2002 en

SIST EN 120005:2002

iTeh STANDARD PREVIEW (standards.iteh.ai)

SIST EN 120005:2002

https://standards.iteh.ai/catalog/standards/sist/836de739-06c3-403e-81d2-4370eeff046c/sist-en-120005-2002

EUROPEAN STANDARD NORME EUROPÉENNE EUROPÄISCHE NORM

EN 120005

July 1992

UDC:

Supersedes CECC 20005 Issue 1:1986

Descriptors: Quality, electronic components, photodiodes

English version

Blank Detail Specification: Photodiodes, photodiode-arrays (Not intended for fibre optic applications)

Spécification Particulière Cadre: Photodiodes, réseaux de photodiodes (Non destinées aux applications pour les fibres optiques)

Vordruck für Bauartspezifikation: Photodioden, Photodioden-Zeilen (Nicht für faseroptische Anwendungen)

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This European Standard was approved by the CENELEC Electronic Components Committee (CECC) on 27 January 1992. CENELEC members are bound to comply with CEN/CENELEC Internal Regulations which stipulate the conditions for giving this European Standard the status of a national standard without any alteration ist-en-120005-2002

Up-to-date lists and bibliographical references concerning such national standards may be obtained on application to the General Secretariat of the CECC or to any CENELEC member.

This European Standard exists in three official versions (English, French, German). A version in any other language made by translation under the responsibility of a CENELEC member into its own language and notified to the CECC General Secretariat has the same status as the official versions.

CENELEC members are the national electrotechnical committees of Austria, Belgium, Denmark, Finland, France, Germany, Greece, Iceland, Ireland, Italy, Luxembourg, Netherlands, Norway, Portugal, Spain, Sweden, Switzerland, and United Kingdom. The membership of the CECC is identical, with the exception of the national electrotechnical committees of Greece, Iceland and Luxembourg.

\mathbf{CECC}

European Committee for Electrotechnical Standardization Comité Européen de Normalisation Electrotechnique Europäisches Komitee für Elektrotechnische Normung

Central Secretariat: rue de Stassart 35, B-1050 Brussels

Foreword

The CENELEC Electronic Components Committee (CECC) is composed of those member countries of the European Committee for Electrotechnical Standardization (CENELEC) who wish to take part in a harmonized System for electronic components of assessed quality.

The object of the System is to facilitate international trade by the harmonization of the specifications and quality assessment procedures for electronic components, and by the grant of an internationally recognized Mark, or Certificate, of Conformity. The components produced under the System are thereby acceptable in all member countries without further testing.

This European Standard was prepared by CECC WG 20, "Opto-Electronic Components and Liquid Crystal Devices".

The text of the draft based on document CECC 20005 Issue 1:1986 was submitted to the formal vote for conversion to a European Standard;

together with the voting report, circulated as ANDARD PREVIEW document CECC(Secretariat)3007 the following documents were approved by CECC as EN 120005 dards.iteh.ai)

on 27 January 1992:

CECC 20005 Issue 1:1986 with Amendment 1

SIST EN 120005:2002

The following dates were fixed: https://standards.iteh.ai/catalog/standards/sist/836de739-06c3-403e-81d2-

- latest date of announcement (doa) 1992;12;22:046c/sist-en-120005-2002 of the EN at national level
- latest date of publication (dop) 1993-06-22 of an identical national standard
- latest date of declaration 1993-06-22 of national standards
- obsolescence
 latest date of withdrawal (dow) 2002-12-22
 of conflicting national
 standards

CECC 20005

Förderverein für Elektrotechnische Normung (FEN) e. V. Förderverein für Elektrotechnische Normung (FEN) e. V.

Cenelec Electronic Components Committee



English version

Harmonized System of Quality Assessment for **Electronic Components**

BLANK DETAIL SPECIFICATION:

PHOTODIODES, PHOTODIODE-ARRAYS (NOT INTENDED FOR FIBRE OPTIC APPLICATIONS) TANDARD PREVIEW

standards.iteh.ai)

Système Harmonisé d'Assurance de la Qualité SIST EN 12 0005:2002 des Composants Electrohiques eh.ai/catalog/standartls/sist/836de739-06c3-403e-81d2-4370eeff046c/sist-en-120005-2002

SPECIFICATION PARTICULIERE CADRE:

PHOTODIODES, RESEAUX DE PHOTODIODES (NON **DESTINEES AUX APPLICATIONS** POUR LES FIBRES OPTIQUES)

> Harmonislertes Gütebestätigungssystem für Bauelemente der Elektronik

VORDRUCK FUR BAUARTSPEZIFIKATION:

PHOTODIODEN, PHOTODIODEN-ZEILEN (NICHT FÜR FASEROPTISCHE ANWENDUNGEN)

Issue Edition Ausgabe

CECC 20005

1986

Foreword

The CENELEC Electronic Components Committee (CECC) is composed of those member countries of the European Committee for Electrotechnical Standardization (CENELEC) who wish to take part in a harmonized System for electronic components of assessed quality.

The object of the System is to facilitate international trade by the harmonization of the specifications and quality assessment procedures for electronic components, and by the grant of an internationally recognized Mark, or Certificate, of Conformity. The components produced under the System are thereby accepted by all member countries without further testing.

This specification has been formally approved by the CECC, and has been prepared for those countries taking part in the System who wish to issue national harmonized specifications for PHOTODIODES, PHOTODIODE-ARRAYS (NOT INTENDED FOR FIBRE OPTIC APPLICATIONS). It should be read in conjunction with the current regulations of the CECC System.

At the date of printing of this document the member countries of the CECC are Austria, Belgium, Denmark, Finland, France, Germany, Ireland, Italy, the Netherlands, Norway, Portugal, Spain, Sweden, Switzerland, and the United Kingdom.

Preface

This blank detail specification was prepared by the CECC Working Group 20: "SEMICONDUCTOR OPTOELECTRONIC AND LIQUID CRYSTAL DEVICES". It is one of a series of blank detail specifications for semiconductor devices, based on the generic specification CECC 20000.

Voting

The text of this blank detail specification was circulated to the CECC for voting in the documents indicated below, and was ratified by the President of the CECC for printing as a CECC Specification.

Document

Voting Date National Standards iteh ai/catalog/standards standards standards iteh ai/catalog/standards standards standards iteh ai/catalog/standards iteh ai/catalog

CECC (Secretariat) 1453 2 April 1984

4370eeff046CECC (Secretariat) 1623

CECC (Secretariat) 1453 2 April 19 CECC (Secretariat) 1454

CECC (Secretariat) 1624

NOTE This specification is published initially in English and French. The German text will follow as soon as it has been prepared.

Texts between square brackets give guidelines on how to fill in the blank detail specification

PHOTODIC	DES, PHOTODIODE-AR	RA	YS (NOT IN	TENDED FOR FIBRE OF	TIC AP	PLIC	ATIO	NS)
		1	Page of	CECC 20005-X	XX		2	
(and possibly specification :	of body from which			[CECC detail specification		er		
specification	is available)			plus issue number and/o	r date]		E	
ELECTRONIC COMPONENT OF (3) ASSESSED QUALITY IN ACCORDANCE WITH: CECC 20000, issue [and national			[National no This box ma includes CE			4		
references if								
1 Mechan	nical description ① Detail specification for						<u>(5)</u>	
		se	structurally	er(s) of relevant device (s similar devices] INFORMATION: see cla			priate	3,
OUTLINE DRAWING AND 2 Short description				lescription			6	
CONNECTIONS (Terminal connected to case, if any) Photod				/photodiode-arrays				
[The outling the device its mounting [may be trans	e drawing may correspond itself and/or the device wit	th ore	Encapsulation Application Power: amb	tor material: S1/ on: metal/glass/plastic/ h.ai) ient-rated (T _{amb}) rtant quick reference data		ii .c.	.dl	
	etters and figures/colour co CCC 20000 and/or clause 6 tion		3 Level (S) of quality assess 05-2002 [if relevant]			8	
_	cation if special method is							
4 Limiting values (Absolute maximum rating system)							9	
	per diode over the operatinat a value shall be inserted	_	_	_	ated.			
Clause	Clause [Repeat only clause numbers used, with text. Additional values, if any,				, ,	Va	lue	
CECC 20005	shall be given at the appropriate should preferably be given in cl		e place without clause number(s). Curves ause 9 of this specification		Symbol	min.	max.	Unit
4.1	Operating ambient temperatures			T_{amb}	X	X	$^{\circ}\mathrm{C}$	
4.2	Storage temperatures			$T_{ m stg}$	X	X	°C	
4.3	Soldering temperature [Soldering time and minimum distance to case shall be given Recommended mounting conditions (temperature, duration) may be given in clause 9.1 of this specification]				$\mathbf{T}_{ ext{sld}}$		X	$^{\circ}\mathrm{C}$
4.4	Reverse voltage				V_{R}		X	$ _{\mathrm{V}}$
4.5	Total power dissipation at ambient temperature of 25 °C with temperature derating curve if necessary (see 9.2)						X	w
	about manufacturers who at CECC 00200: Qualified I			s qualified to this detail s	pecifica	tion is	avail	able

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5 Electrical and optical characteristics

See clause 8 of this specification for inspection requirements (Groups A and C)

[Signs between brackets correspond to characteristics given as "where appropriate" or as alternatives:

- Those characteristics marked "where appropriate" in this clause <u>and</u> in the inspection section shall either be omitted or, if specified, shall then be measured.
- For equivalent characteristics given as alternatives, the choice should preferably be left open to allow the use of the same detail specification by different manufacturers or countries.

Repeat only clause numbers used, with text. Any additional characteristics to be given at appropriate place but without clause number.

When several devices are defined in the same detail specification, the relevant values should be given on successive lines, where possible avoiding repetition of identical values.]

Clause CECC M	Measured	Characteristics and conditions, at $T_{amb} = 25~^{\circ}C$		Value		
20005		unless otherwise stated	Symbol	min.	max.	Unit
5.1.1 and/or	A2b	Reverse current under irradiation at specified V_{R} and E_{e} or E_{v} (see Note 4)	$I_R(H)(1)$ $I_R(e)(1)$	X		μА
5.1.2 and/or	A2b	Responsivity at a specified wavelength in the visible region for a given bandwidth $\Delta\lambda$ at specified V_R and E_e	S(1)	X		A/W
5.1.3	A2b	Responsivity at a specified wavelength in the infrared region for a given bandwidth $\Delta\lambda$ at specified V_R and E_e	S(2)	X		A/W
5.2	C2a	Where appropriate: Reverse current under irradiation at specified V_R and E_e or E_v (see Note 4)	$I_R(H)(2)$ $I_R(e)(2)$		(X)	μA
5.3	A2b	For arrays, matching factor of diodes, under specified conditions: $ \frac{SIST EN 120005:2002}{SIST EN 120005:2002} $ $ m = \frac{I_R(H) \text{ (highest)}}{I_R(H) \text{ (lowest)}} \underbrace{\frac{4370}{1}_{R}(e) \text{ (lowest)}}_{I_R(e) \text{ (lowest)}} \text{ or } \frac{1}{I_R(e) \text{ (lowest)}} $	-403e-81d	2-		
		$rac{\mathrm{S}(1) \; (\mathrm{highest})}{\mathrm{S}(1) \; (\mathrm{lowest})} \mathrm{or} rac{\mathrm{S}(2) \; (\mathrm{highest})}{\mathrm{S}(2) \; (\mathrm{lowest})}$	m		X	
5.4	A2b	Reverse dark current at specified V_R and irradiance $E_e=0$	$I_R(1)$		X	nA
5.5	A3	Reverse dark current at specified V_R irradiance $E_e = 0$ and specified T_{amb}	$I_R(2)$		X	μΑ
5.6	C2a	Rise time under specified V, I_R , λ_p , $\Delta\lambda$, R, t_w and δ	$\mathbf{t_r}$		X	μs
5.7	C2a	Fall time under specified V, I_R , λ_p , $\Delta\lambda$, R, t_w and δ	$\mathbf{t_f}$		X	μs
5. 8	C2a	Where appropriate: Junction capacitance at V_R specified preferably $V_R=0$, f to be specified, $E_e=0$	C_{tot}		(X)	pF
5.9		Reverse current under irradiation versus illuminance E_{ν} or irradiance E_{e} (see Note 4) expressed as a curve at specified V_{R} (see 9.4)	ŧ			
5.10	٠	Responsivity diagram at specified V_R (see 9.4)				
5.11		Relative responsivity expressed as a curve at specified V_{R} and E_{e} (see 9.5)				
Notes on	page 7					

6 Marking

[Information actually marked on the device and on the primary pack.]

[Any particular information other than given in box ⑦ on front page and/or 2.5 of CECC 20000 shall be specified here.]

7 Ordering information

The following minimum information is necessary to order a specific device, unless otherwise specified:

- type number
- CECC reference of detail specification with issue number and/or date when relevant
- any other particulars.

8 Test conditions and inspection requirements

These are given in the following tables, where the values and exact test conditions to be used should be specified as required for a given type, and as required by the relevant test in CECC 20000. [X shows that a value is to be inserted in the detail specification.]

[When several devices are included in the same detail specification, the relevant conditions and/or values should be given on successive lines, where possible avoiding repetition of identical conditions and/or values.

The choice between alternative tests should preferably be left open, unless very sound technical reasons forbid this. Although such tests are not strictly equivalent, they are meant to achieve the same results which are to assess the correct manufacture of a device. Alternatives are provided to take into account different equipments or methods of measurement used in various countries.]

In this section, reference to clause numbers are made with respect to CECC 20000, unless otherwise stated.

GROUPA Lot by lot

All tests are non destructive (3:5.6)/catalog/standards/sist/836de739-06c3-403e-81d2-

	-	4370eeff046c/sist-en-120005-2002			Inspection					
Examination or test (Ref. 4.3.4/)		Conditions at T_{amb} = 25 °C unless otherwise stated			Limits (see Note 1)			Assessment		
						min.	max.	Unit	п	AQL
SUB-GROUP A1									Ι	1,5 %
Visual inspection		4.2.1								
SUB-GROUP A2a Non-operative devices			State releva See Note 2	nt limit	<u>s</u>				II	0,15 %
SUB-GROUP A2b									II	0,65 %
$I_{R}(1)$	(P-002)	$V_R = V_R \text{ max.}$	$\mathbf{E_e} = 0$				X	nA		
$I_R(H)(1), I_R(e)(1)$ and/or	(P-001)	$V_R =$	E_{V} or E_{e} =			X		μA		
S(1), S(2)	(P-001)	$V_R =$	$\mathbf{E_e} =$	$\lambda_p =$	$\Delta \lambda =$	X		A/W		
m (for arrays)	(P-001)	$V_R =$	E_{V} or E_{e} =			A	X	_		
SUB-GROUP A3										
$I_R(2)$	(P-002)	$egin{array}{l} V_{ m R} = \ T_{ m amb} = \end{array}$	$E_e = 0$				X	μΑ	II	1,5 %
Notes on page 7		<u> </u>								